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•	Application No.	Applicant(s)	
Notice of Allowability	10/770,278	MOUMEN, NAIM	
	Examiner	Art Unit	
	Yennhu B. Huynh	2813	
The MAILING DATE of this communication ap All claims being allowable, PROSECUTION ON THE MERITS herewith (or previously mailed), a Notice of Allowance (PTOL-8 NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT of the Office or upon petition by the applicant. See 37 CFR 1.3	IS (OR REMAINS) CLOSED in the B5) or other appropriate communities. This application is sufficient in the B5.	his application. If not include ication will be mailed in due o	d course. THIS
1. This communication is responsive to 2/2/04.			
2. X The allowed claim(s) is/are 14-20.			
3. $igotimes$ The drawings filed on <u>02 February 2004</u> are accepted b	y the Examiner.		
 4. Acknowledgment is made of a claim for foreign priority a) All b) Some* c) None of the: 1. Certified copies of the priority documents had 2. Certified copies of the priority documents had 3. Copies of the certified copies of the priority International Bureau (PCT Rule 17.2(a)). * Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DAT"	ave been received. ave been received in Application documents have been received i	No n this national stage applicati	
noted below. Failure to timely comply will result in ABANDO THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.	NMENT of this application.		
5. A SUBSTITUTE OATH OR DECLARATION must be sui INFORMAL PATENT APPLICATION (PTO-152) which (OTICE OF
6. CORRECTED DRAWINGS (as "replacement sheets") n	nust be submitted.		
(a) including changes required by the Notice of Draftsp	-	PTO-948) attached	
1) hereto or 2) to Paper No./Mail Date		the Office action of	
(b) including changes required by the attached Examin Paper No./Mail Date	ier's Amendment / Comment or ii	t the Office action of	
Identifying indicia such as the application number (see 37 CF each sheet. Replacement sheet(s) should be labeled as such			back) of
 DEPOSIT OF and/or INFORMATION about the de attached Examiner's comment regarding REQUIREMEN 			ote the
Attachment(s) 1. ⊠ Notice of References Cited (PTO-892) 2. □ Notice of Draftperson's Patent Drawing Review (PTO-94	8) 6. 🗌 Interview Sun Paper No./M	ail Date	ı-152)
 Information Disclosure Statements (PTO-1449 or PTO/S Paper No./Mail Date <u>2/2/04</u> 	•	mendment/Comment	
 Examiner's Comment Regarding Requirement for Depos 		tatement of Reasons for Allov	vance
of Biological Material	9.	CARL WHITEHEAD, JR. SUPERVISORY PATENT EXAM TECHNOLOGY CENTER 28	AINEF:

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DETAILED ACTION

This Office Action is in response to the Preliminary Amendment filed on 02/02/04.

Claims 1-13 are cancelled by the Preliminary Amendment filed on 02/02/04.

Information Disclosure Statement

The information disclosure statement filed on 2/2/04 is being considered by the examiner.

Oath/Declaration

Oath/Declaration filed on 2/2/04 is accepted.

EXAMINER'S AMENDMENT

An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Leslie Szivos on 03/27/05.

The claim has been changed as follows:

In claim 15 lines 2, the recited limitation --25/min-- changed to -- 25Angstroms/min--.

Allowable Subject Matter

Claims 14-20 are allowable over the prior art of record.

The following is an examiner's statement of reasons for allowance: Prior art of record does not disclose a method of a collar formation using selective SiGe/Si etch,

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which include the steps of etching a structure containing exposed surface of amorphous Si and SiGe with an aqueous solution of HF to remove oxide from the exposed surface; and etching the exposed amorphous Si surfaces with an aqueous NH₄OH to selectively remove the amorphous Si at a faster than the SiGe.

Burns et al. (6,258,679B1) disclose etching a structure containing an amorphous silicon and SiGe with a highly selective HF for remove oxide layer on the exposed surface, but not with an aqueous HF (col.4 lines 45-53).

Mercaldi et al. (6,316,370) disclose etching a structure containing an amorphous silicon or SiGe with a highly selective HF acid (or aqueous HF) but not for remove oxide layer on the exposed surface (col.3 lines 34-44 and col. 4 lines 28-35 and 55-60).

Aspnes et al. (US. 4,380,490) disclose etching a structure containing an Si and Ge substrate, but do not disclose amorphous silicon and SiGe, wherein the etching use with highly selective HF to remove oxide. Aspnes also disclose etching the substrate with NH₄OH (col.3 & 4), but do not disclose wherein the aqueous NH4OH remove the silicon faster than the germanium.

Sakaguchi et al. (US 5,277,748) disclose etching a substrate containing Si but not amorphous silicon, and SiGe with HF etching, wherein the etching rate on Si is higher than SiGe (col. 3 & 4 lines 50-9), but do not disclose the etching is used by NH₄OH.

Therefore the above reference is improperly combined with each other.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably Art Unit: 2813

Conclusion

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Yennhu B. Huynh whose telephone number is 571-272-1692. The examiner can normally be reached on M-F 8.30AM-7.00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead, Jr., can be reached 571-272-1702. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7724 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

YNBH,

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